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Bib Data Sheet

**CONFIRMATION NO. 7302** 

SERIAL NUMBE 09/942,038			CLASS 438		GROUP ART UNIT 2813		ATTORNEY DOCKET NO. 0819-0637			
APPLICANTS										
Yoshihiro Mo										
Yasutoshi Ok Akihiko Tsuz										
** CONTINUING DATA **********************************										
** FOREIGN APPLICATIONS ************************************										
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 10/15/2001										
Foreign Priority claimed STATE OR					SHEETS TO		TAL	INDEPENDENT		
Verified and Acknowledged Examiner's Signature Initials COUNTRY					DRA			AIMS 15	CLAIMS 4	
ADDRESS 22204 NIXON PEABODY, LLP 401 9TH STREET, NW SUITE 900 WASHINGTON, DC 20004-2128										
TITLE  Method for fabricating semiconductor device including annealing an electrode in a reducing atmosphere before capacitor insulating film forming										
						☐ All F	ees	*		
						1.16 Fees (Filing)				
FILING FEE	EES: Authority has been given in Paper lo to charge/credit DEPOSIT ACCOUNT				1.17 Fees ( Processing Ext. of time )  1.18 Fees ( Issue )  Other Credit					
RECEIVED N	No for following:									